

Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at www.onsemi.com

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild guestions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officer



December 2012

FAN104W High-Frequency Primary-Side-Regulation PWM Controller

Features

- Achieves <30 mW; Energy Star's 5-Star Level
- Proprietary 500 V High-Voltage JFET Startup Reduces Startup Resistor Loss
- Low Operation Current in Burst Mode: 600 μA
- Constant-Voltage (CV) and Constant-Current (CC)
 Control without Secondary-Feedback Circuitry
- Green Mode: PWM Frequency Linearly-Decreasing
- PWM Frequency at 85 kHz with Frequency Hopping to Solve EMI Problem
- Boundary-Conduction-Mode (BCM) Operation at Lower AC Input Voltage
- Cable Compensation in CV Mode
- Cycle-by-Cycle Current Limiting
- Gate Output Maximum Voltage Clamped at 14 V
- V_{DD} Under-Voltage Lockout (UVLO) Available
- Built-in Protections:
 - Output Short-Circuit Protection
 - Output Over-Voltage-Protection (VSOVP) with Latch Mode
 - V_{DD} Over-Voltage-Protection (V_{DD} OVP)
 - CS Pin Single-Fault Protection
 - VS Pin single-Fault Protection
 - Over-Temperature-Protection (OTP) with Latch Mode
- SOIC Package

Description

This highly integrated PWM controller, FAN104W, provides several features to enhance the performance of low-power flyback converters. The proprietary topology of FAN104W enables simplified circuit design for battery charger applications. The result is a lower-cost, smaller, and lighter charger compared to a conventional design or a linear transformer.

To minimize standby power consumption, a proprietary green-mode function provides off-time modulation to linearly decrease PWM frequency under light-load conditions. Green Mode assists the power supply in meeting power conservation requirements.

By using FAN104W, a charger can be implemented with few external components and minimized cost. An output CV/CC characteristic envelope is shown in Figure 1.

Applications

- Battery chargers for smart phones, Pad, PDA, digital cameras.
- Best choice to replace linear transformer and RCC SMPS

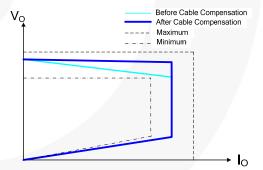


Figure 1. Typical Output V-I Characteristic

Ordering Information

Part Number	Operating Temperature Range	Package	Packing Method
FAN104WMX	-40°C to +105°C	8-Lead, Small Outline Integrated Circuit (SOIC), JEDEC MS-012, .150-Inch Narrow Body	Tape & Reel

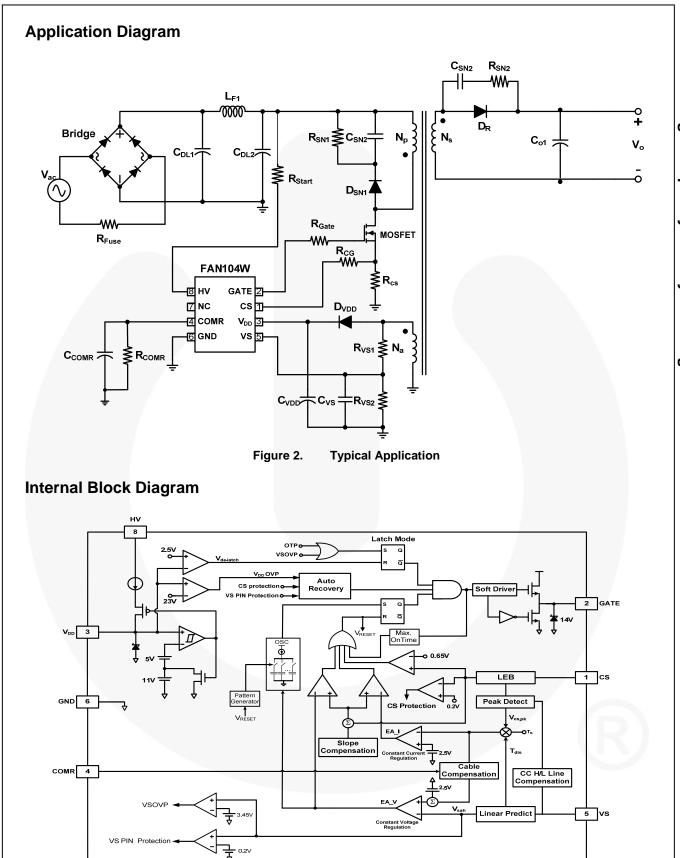
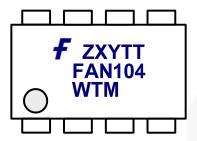


Figure 3.

V_{sah}= Output voltage feedback signal

Functional Block Diagram

Marking Information



F: Fairchild Logo

Z: Plant Code

X: 1-Digit Year Code

Y: 1-Digit Week Code

TT: 2-Digit Die Run Code T: Package Type (M=SOP)

M: Manufacture Flow Code

Figure 4. Top Mark

Pin Configuration

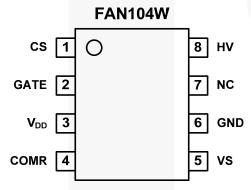


Figure 5. Pin Configuration

Pin Definitions

Pin#	Name	Description
1	CS	Current Sense. This pin connects a current sense resistor to detect the MOSFET current for peak-current-mode control in Constant Voltage (CV) regulation and provides the output-current regulation in constant current regulation.
2	GATE	PWM Signal Output . This pin uses the internal totem-pole output driver to drive the power MOSFET.
3	V_{DD}	Power Supply . IC operating current and MOSFET driving current are supplied using this pin. This pin is connected to an external V_{DD} capacitor. The threshold voltages for startup and turn-off are 16 V and 5 V, respectively. The operating current is lower than 3.5 mA.
4	COMR	Cable Compensation . Connect a capacitance and resistor between this pin and the GND pin for compensation voltage drop due to output cable loss in CV regulation.
5	VS	Voltage Sense. This pin detects the output voltage information and discharge time for Constant Voltage (CV) and Constant Current (CC) regulation. This pin connects a divider resistor from the transformer of auxiliary winding.
6	GND	Ground
7	NC	No Connect
8	HV	High Voltage. This pin connects to bulk capacitor for high-voltage startup.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Paran	Min.	Max.	Unit	
V_{HV}	HV Pin Input Voltage			500	V
V_{VDD}	DC Supply Voltage ^(1,2)			30	V
V _{VS}	VS Pin Input Voltage		-0.3	7.0	V
V _{CS}	CS Pin Input Voltage		-0.3	7.0	V
V _{COMR}	Voltage Error Amplifier Output Volta	ge	-0.3	7.0	V
V _{HV}	HV Pin Input Voltage			500	V
P_D	Power Dissipation (T _A < 50°C)		660	mW	
R _{⊖JA}	Thermal Resistance (Junction-to-Air)			127	°C/W
R⊕JC	Thermal Resistance (Junction-to-Ca		27	°C/W	
T_J	Operating Junction Temperature			150	°C
T _{STG}	Storage Temperature Range			150	°C
TL	Lead Temperature (Soldering 10 Seconds)			260	°C
FCD	Electrostatic Discharge Capability	Human Body Model, JEDEC:JESD22 A114 (Except HV Pin) ⁽³⁾	6	6	kV
ESD		Charged Device Model, JEDEC:JESD22 C101 (Except HV Pin) ⁽³⁾		2	KV

Notes:

- 1. Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device.
- 2. All voltage values, except differential voltages, are given with respect to GND pin.
- 3. ESD ratings including HV pin: HBM=1 kV, CDM=1.25 kV.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
T _A	Operating Ambient Temperature		105	°C

Electrical Characteristics

 $V_{DD}\text{=}15V,\,T_{A}\text{=}25\,^{\circ}\text{C},\,\text{unless otherwise specified}.$

Symbol	Parameter		Condition	Min.	Тур.	Max.	Unit
V _{DD}							
V_{OP}	Continuously Operating Voltage ⁽⁴⁾				21		V
$V_{\text{DD-ON}}$	Turn-On Thres	shold Voltage		15	16	17	V
$V_{DD\text{-}OFF}$	Turn-Off Thres	shold Voltage		4.5	5.0	5.5	V
$V_{\text{DD-HV-ON}}$	HV JFET Turn Voltage ⁽⁴⁾	-On Threshold			4.2		V
V _{DD} -	De-latch Thres	shold Voltage ⁽⁴⁾			2.5		V
I _{DD-OP}	Operating Curr	rent	V _{DD} =15 V, V _{CS} =4 V, V _{VS} =2.6 V, V _{COMR} =4 V	2.5	3.5	4.5	mA
I _{DD-ST}	Startup Curren	t	V _{DD} =V _{DD-ON} – 0.16 V			100	μA
I _{DD-GREEN}	Green-Mode C	perating Current	V _{DD} =8.5 V, V _{CS} =4 V, V _{VS} =2.5 V, V _{COMR} =0V	500	600	700	μΑ
$V_{\text{DD-OVP}}$	V _{DD} Over-Voltage-Protection Level		V_{DD} =0 V \rightarrow V $_{DD-OVP}$, V $_{CS}$ =0.25 V, V $_{VS}$ =0.4 V, V $_{COMR}$ =0 V	21.5	23.0	24.5	V
t _{D-VDDOVP}	V _{DD} Over-Voltage-Protection Debounce Time ⁽⁴⁾		V _{DD} = 20 V→30 V, V _{CS} =0 V	50	100	150	μs
HV Section	on					•	
$V_{\text{HV-MIN}}$	Minimum Startup Voltage on HV Pin ⁽⁴⁾					50	V
I _{HV}	Supply Curren	t Drawn from HV Pin	V _{AC} =90 V (V _{DC} =100 V)	1	3	5	mA
I _{HV-LC}	Leakage Current after Startup		HV=500 V, V _{DD} →V _{DD} - _{ON} →V _{DD-OFF} +1V		1.25	3.00	μΑ
Oscillato	Section						
f _{osc}	Frequency	Center Frequency	V _{DD} =15 V, V _{CS} =4 V, V _{VS} =2.5 V, V _{COMR} =3.5 V	80	85	90	kHz
000		Hopping Range		±2	±3	±4	11112
t _{FHR}	Frequency Ho	pping Period ⁽⁴⁾		2	3	4	ms
f _{OSC-N-MIN}	Minimum Frequency at No-Load in Constant Voltage (CV) Mode		V _{DD} =15 V, V _{CS} =4 V, V _{VS} =2.5 V, V _{COMR} =0 V	1.1	1.2	1.3	kHz
f _{OSC-CC-MIN}	Minimum Frequency in Constant Current (CC) Mode ⁽⁵⁾		V _{DD} =15 V, V _{CS} =4 V, V _{VS} =0 V, V _{COMR} =3.5 V	39	44	49	kHz
f _{OSC-BCM}	Minimum Frequency for Boundary Conduction Mode (BCM) Operation		V _{DD} =15 V, V _{CS} =0 V, V _{VS} =0 V, V _{COMR} =4 V	6	10	14	kHz
f_{DV}	Frequency Variation vs.V _{DD} Deviation ⁽⁴⁾		V _{DD} =10 V or 25 V, V _{CS} =4 V, V _{VS} =2.5 V, V _{COMR} =3.5 V			2	%
f _{OSC-T}	Frequency Var Temperature D	riation vs. Deviation ⁽⁴⁾	V _{DD} =15 V, T _A =-40°C~125°C	-12		12	%

Continued on the following page...

Electrical Characteristics (Continued)

 V_{DD} =15V, T_A =25 $^{\circ}$ C, unless otherwise specified.

Symbol	Parameter	Condition		Тур.	Max.	Unit
Voltage-S	Sense				•	
I _{TC}	Bias Current	V _{CS} =4 V, V _{VS} =0 V, Measure I _{VS}	9	10	11	μA
$I_{VS\text{-}UVP}$	Brownout Protection Current ⁽⁴⁾			250		μA
V _{VS-CM-MIN}	VS Threshold Voltage of ZCD Undetectable Protection ⁽⁴⁾			0.55		V
V _{VS-CM-MAX}	VS Threshold Voltage of ZCD Undetectable Protection ⁽⁴⁾			0.75		V
t _{VS-BLANK}	ZCD Blanking Time		1.10	1.45	1.80	μs
V _{VS-OFFSET}	ZCD Turn Off Threshold ⁽⁴⁾			0.2		V
V _{VSOVP}	V _S Over-Voltage Protection		3.30	3.45	3.60	V
T _{VSOVP}	V _S Over-Voltage Protection Debounce Time ⁽⁴⁾		i	3		Cycle
Current-S	Sense					
V_{STH}	Threshold Voltage for Current Limit	V _{COMR} =4 V, V _{VS} =0.9 V, CS Pin Input Ramp until Gate OFF	0.60	0.65	0.70	V
V _{STH-VA}	Threshold Voltage for Current Limit when ZCD Undetectable			0.30	0.35	V
t _{LEB}	CS Leading Edge Blanking Time	V _{COMR} =4V		150		ns
Voltage-E	rror-Amplifier					
V_{VR}	Reference Voltage	V _{CS} =4 V, V _{DD} =16 V→26 V Measure V _{COMR}	2.475	2.500	2.525	V
V _{CCR}	Variation Test Voltage for CC Mode Regulation	V_{CS} =0.463 V, V_{VS} =4 V, V_{DD} =26 V \rightarrow 10 V, Measure V_{COMR}	2.380	2.430	2.480	V
V _{SN-CC}	VS Sampling Voltage to Start Frequency Decreasing in CC Mode	V_{CS} =4 V, f_{S1} = f_{OSC} -2 kHz, V_{COMR} =3.5 V, Adjust V_{VS}	2.2	2.3	2.4	V
$V_{\text{SG-CC}}$	VS Sampling Voltage to End Frequency Decreasing in CC Mode	V_{CS} =4 V, f_{S2} = f_{OSC} +2 kHz V_{COMR} =3.5 V, Adjust V_{VS}	0.4	0.8	1.1	٧
S _{G-CC}	Frequency Decreasing Slope of CC Mode	S _{G-CC} =(f _{S1} -f _{S2}) / (V _{SN-CC} -V _{SG-CC})	16	28	46	KHz/V
V _{SN-CV}	Starting Voltage of Frequency Decreasing in CV Mode	V _{CS} =4 V, V _{VS} =2.5 V, Adjust V _{COMR}	2.5	2.9	3.3	V
$V_{\text{SG-CV}}$	Ending Voltage of Frequency Decreasing in CV Mode	V_{CS} =4 V, V_{VS} =2.5 V, Adjust V_{COMR}	0.3	0.5	0.7	V
S _{G-CV}	Frequency Decreasing Slope of CV Mode		25	36	47	kHz/V
t _{ON-MIN-H}	Minimum On-Time at High Line in CV Mode	V _{VS} =0.9 V, V _{CS} =0.25 V	370	400	430	ns
t _{ON-MIN-L}	Minimum On-Time at Low Line in CV Mode		0.75	0.90	1.05	μs
t _{ON-MIN-SAT}	Minimum On-Time at Low Line in CV Mode		1.05	1.20	1.35	μs

Continued on the following page...

Electrical Characteristics (Continued)

 V_{DD} =15 V, T_A =25 $^{\circ}$ C, unless otherwise specified.

Symbol	Parameter	Condition	Min.	Тур.	Max.	Unit	
Cable Co	Cable Compensation						
V_{COMR}	Variation Test Voltage on COMR Pin for Cable Compensation	V _{CS} =4 V, V _{VS} =4 V, Measure V _{COMR}	1.00	1.15	1.30	٧	
Gate							
t _{ON-MAX}	Maximum On-Time	V _{DD} =15 V, V _{CS} =0 V, V _{VS} =0 V, V _{COMR} =4 V	13	15	18	μs	
V _{OL}	Output Voltage Low ⁽⁴⁾	V _{DD} =20 V			1.5	V	
V _{OH}	Output Voltage High ⁽⁴⁾	V _{DD} =0 V→18 V→8 V	5			V	
$V_{\text{OH-MIN}}$	Output Voltage High ⁽⁴⁾	V _{DD} =5.5 V	4			V	
t _{PD}	Propagation Delay to GATE Output	V _{DD} =7.5 V	100	150	200	ns	
t _r	Gate Output Rising Time	V _D =15 V, C _{Load} =1 nF	100	150	200	ns	
t _f	Gate Output Falling Time	V _{DD} =15 V, C _{Load} =1 nF	50	75	100	ns	
V_{CLAMP}	Output Clamp Voltage	V _{DD} =2V	12.5	14.0	15.5	V	
Over-Tem	Over-Temperature Protection (OTP)						
T _{OTP}	Threshold Temperature for OTP ⁽⁴⁾⁽⁶⁾				150	°C	
T _{OTP-HYS}	Restart Junction Temperature ⁽⁴⁾⁽⁶⁾			120		°C	

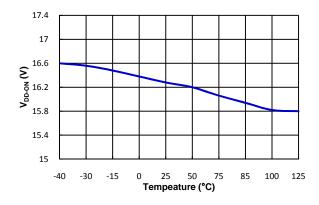
Notes:

- Not tested; guaranteed by design.

 fosc-cc-min occurs when the power unit enters BCM operation.

 OTP and VSOVP protection are Latch Mode.

Typical Performance Characteristics



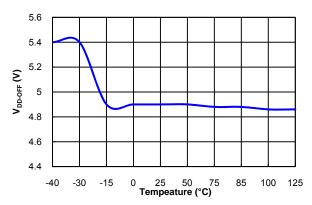
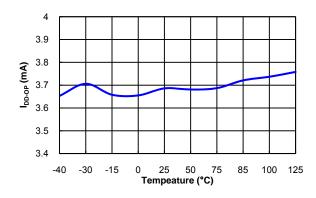


Figure 6. V_{DD} Turn-On Threshold Voltage (V_{DD-ON}) vs. Temperature

Figure 7. V_{DD} Turn-Off Threshold Voltage (V_{DD-OFF}) vs. Temperature



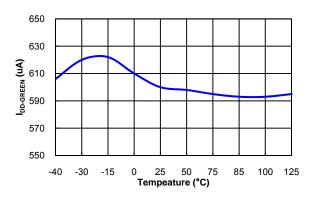
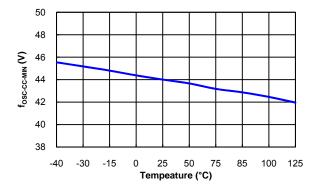


Figure 8. Operating Current (I_{DD-OP}) vs. Temperature

Figure 9. Burst Mode Operating Current (I_{DD-GREEN}) vs. Temperature



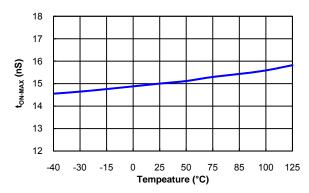
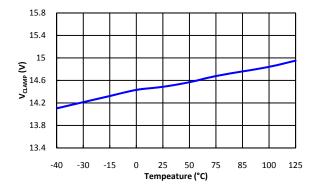


Figure 10. CC Regulation Minimum Frequency (fosc-cc-MIN) vs. Temperature

Figure 11. Maximum Gate On Time (t_{ON-MAX}) vs. Temperature

Typical Performance Characteristics (Continued)



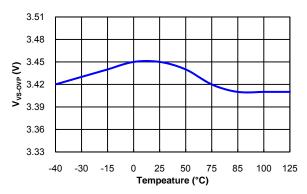
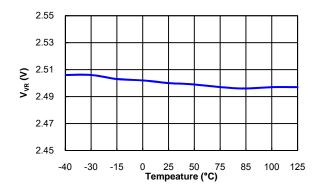


Figure 12. Gate Output Clamp Voltage (V_{CLAMP}) vs. Temperature

Figure 13. VS Over-Voltage Protection (V_{VS-OVP}) vs. Temperature



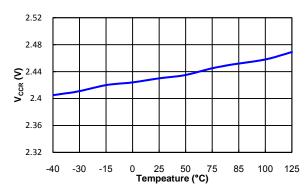
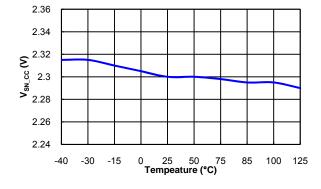


Figure 14. Reference Voltage of CS (V_{VR}) vs. Temperature

Figure 15. Variation Voltage on CS Pin for Constant-Current Regulation (V_{CCR}) vs. Temperature



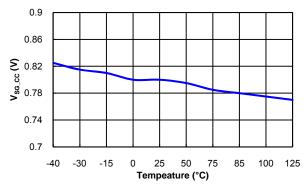
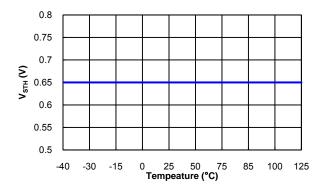


Figure 16. Starting Voltage of Frequency Decreasing of CC Regulation (V_{SN-CC}) vs. Temperature Figure 17. Ending Voltage of Frequency Decreasing of CC Regulation (V_{SG-CC}) vs. Temperature

Typical Performance Characteristics (Continued)



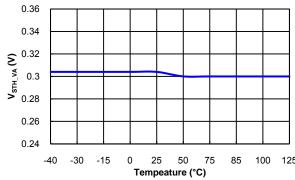
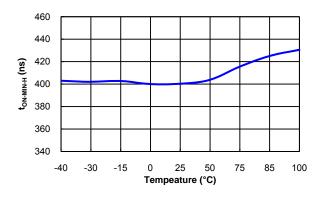


Figure 18. Threshold Voltage for Current Limit (V_{STH}) vs. Temperature

Figure 19. Threshold Voltage for Current Limit at Power Mode (V_{STH-VA}) vs. Temperature



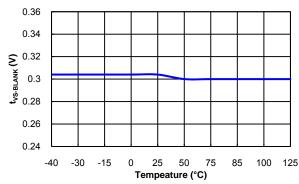


Figure 20. Minimum On Time (t_{ON-MIN-H}) vs. Temperature

Figure 21. V_S Leading-Edge Blanking Time (t_{VS-BLANK}) vs. Temperature

Functional Description

Basic CV/CC Control Principle

Figure 22 shows the basic circuit diagram of a Primary-Side Regulated (PSR) flyback converter with typical waveforms shown in Figure 23. Generally, Discontinuous Conduction Mode (DCM) or Boundary Conduction Mode (BCM) operation is preferred for PSR since it allows better output regulation. The operation principles of DCM/BCM flyback converter are as follows:

During the MOSFET on time (t_{ON}), input voltage (V_{DL}) is applied across the primary-side inductor (L_m). Then MOSFET current (I_{DS}) increases linearly from zero to the peak value (I_{pk}). During this time, the energy is drawn from the input and stored in the inductor.

When the MOSFET is turned off, the energy stored in the inductor forces the secondary diode (D_{sec}) to turn on. While the diode is conducting, the output voltage (V_o), together with diode forward voltage drop (V_F), are applied across the secondary-side inductor ($L_m \times N_s^2 / N_p^2$) and the diode current (I_D) decreases linearly from the peak value ($I_{pk} \times N_p / N_s$) to zero. At the end of inductor current discharge time (I_{DIS}), all the energy stored in the inductor has been delivered to the output.

When the diode current reaches zero, the transformer auxiliary winding voltage (V_{Aux}) begins to oscillate by the resonance between the primary-side inductor (L_m) and the effective capacitor loaded across MOSFET. For BCM operation, this period does not exist.

During the inductor current discharge time, the sum of output voltage and diode forward-voltage drop is reflected to the auxiliary winding side as $(V_o+V_F) \times N_{Aux}/N_s$. Since the diode forward-voltage drop decreases as current decreases, the auxiliary winding voltage reflects the output voltage best at the end of diode conduction time, where the diode current diminishes to zero. By sampling the winding voltage at the end of the diode conduction time, the output voltage information can be obtained. The internal error amplifier for output voltage regulation (EAV) compares the sampled voltage with internal precise reference to generate error voltage (COMV), which determines the duty cycle of the MOSFET in CV Mode.

Meanwhile, the output current is obtained by averaging the triangular output diode current area over a switching cycle as:

$$I_{O} = \langle I_{D} \rangle_{AVG} = \frac{1}{2} \cdot I_{PK} \cdot \frac{N_{P}}{N_{S}} \cdot \frac{T_{DIS}}{T_{S}}$$
 (1)

The internal FAN104W circuits identify the peak value of the drain current with a peak detection circuit and calculate the output current using the inductor discharge time (t_{DIS}) and switching period (t_S). This output information (EAI) is compared with internal precise reference to generate error voltage (COMI), which determines the duty cycle of the MOSFET in CC Mode. With Fairchild's TRUECURRENT® technique, constant current output can be precisely controlled.

With a given current sensing resistor, the output current can be programmed as:

$$I_o = \frac{1.25}{K} \cdot \frac{N_p}{N_s} \cdot \frac{1}{R_{CS}}$$
 (2)

where K is the design parameter of IC, which is 10.5.

Of the two error voltages, COMV and COMI, the smaller one determines the duty cycle. During Constant Voltage regulation, COMV determines the duty cycle while COMI is saturated to HIGH. During Constant Current regulation, COMI determines the duty cycle while COMV is saturated to HIGH.

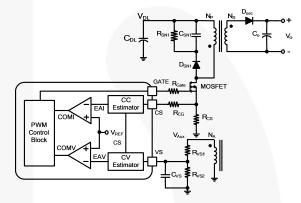


Figure 22. Simplified PSR Flyback Converter Circuit

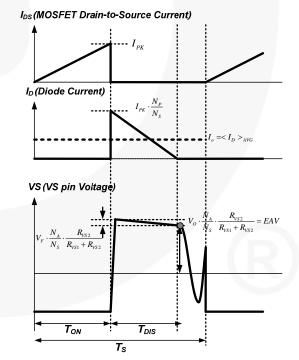


Figure 23. DCM Flyback Converter Waveforms

BCM Operation Function

FAN104W allows BCM operation for better conversion efficiency and low standby power design margin. BCM delays the next cycle turn-on of MOSFET until the discharge time (t_{DIS}) on the VS pin is obtained, as shown in Figure 24. To utilize BCM, FAN104W prohibits the turn-on of next switching cycle for 10% of its switching period after discharge time (t_{DIS}) is obtained. In Figure 24, the first switching cycle has a discharge time (t_{DIS}) before 90% of its original switching period and therefore the turn-on instant of the next cycle is determined its original switching period without being affected by the discharge time (t_{DIS}) point. The second switching cycle does not have discharge time (tDIS) points by the end of its original switching period. Thus, the turn-on of the third switching cycle occurs after discharge time (t_{DIS}) points is obtained, with a delay of 10% of its original switching period. The minimum switching frequency that BCM allows is 10 kHz (fosc-BCM). If the discharge time point is not given until the end of maximum switching period of 100 µs (10 kHz), the converter can go into CCM operation losing output regulation.

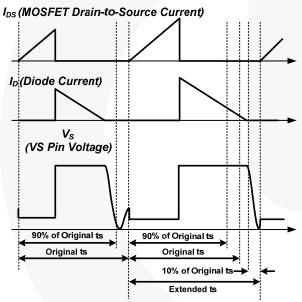


Figure 24. BCM Operation Function Waveform

Green-Mode Operation in CV Mode

The FAN104W uses a voltage regulation error amplifier output (COMV) as an indicator of the output load and modulates the PWM frequency. The switching frequency decreases as load decreases. In heavy load conditions, the switching frequency is fixed at 85 kHz. Once COMV decreases below 2.9 V, PWM frequency linearly decreases from 85 kHz. When FAN104W enters "deep" Green Mode, the PWM frequency is reduced to a minimum frequency (fosc-N-MIN) of 1.2 kHz, saving power to meet international power conservation requirements.

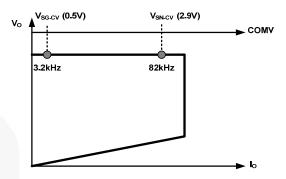


Figure 25. Frequency Reduction with COMV

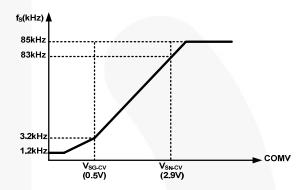


Figure 26. Frequency Reduction Curve in CV Mode

Frequency Reduction in CC Mode

The discharge time ($t_{\rm DIS}$) of diode current increases as the output voltage decreases in CC Mode.FAN104W decreases switching frequency as output voltage drops, as shown in Figure 27. FAN104W indirectly monitors the output voltage by the sample-and-hold voltage (EAV) of V_S, which is taken at 70% of diode current discharge time of the previous switching cycle. Figure 28 shows how the frequency reduces as the sample-and-hold voltage (EAV) of V_O decreases.

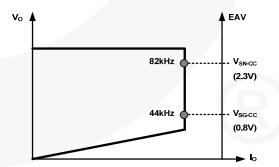


Figure 27. Frequency Reduction with EAV

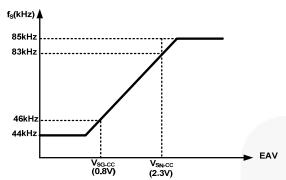


Figure 28. Frequency Reduction Curve in CC Mode

Frequency Hopping

EMI reduction is accomplished by frequency hopping, which spreads the energy over a wider frequency range than the bandwidth of the EMI test equipment, allowing conformation to EMI limitations. The FAN104W internal frequency-hopping circuit changes the switching frequency progressively between 82 kHz and 88 kHz with a period t_{FHR} of 3 ms.

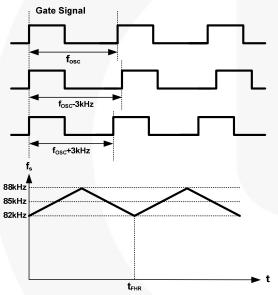


Figure 29. Frequency Hopping

Slope Compensation

The sensed voltage across the current-sense resistor is used for Current-Mode control and pulse-by-pulse current limiting. A synchronized ramp signal with positive slope is added to the current sense information at each switching cycle, improving noise immunity of Current-Mode control.

Cable Voltage Drop Compensation

When it comes to cellular phone charger applications, the battery is located at the end of cable, which typically causes several percentage of voltage drop on the actual battery voltage. FAN104W has a built-in cable voltage drop compensation, which provides a constant output voltage at the end of the cable over the entire load range in CV Mode. As load increases, the voltage drop across the cable is compensated by increasing the reference voltage of voltage regulation error amplifier.

Operating Current

The operating current in FAN104W is as small as 3.5 mA. The small operating current results in higher efficiency and reduces the V_{DD} hold-up capacitance requirement. Once FAN104W enters deep Green Mode, the operating current is reduced to 600 μA , assisting the power supply meet power conservation requirements.

High-Voltage Startup

Figure 30 shows the HV-startup circuit for FAN104W applications. The HV pin is connected to the line input or bulk capacitor through a resistor, R_{Start} (100 k Ω is recommended). During startup, the internal startup circuit is enabled. Meanwhile, line input supplies the current I_{HV}, to charge the hold-up capacitor, C_{VDD} through R_{Start}. When the V_{DD} voltage reaches V_{DD-ON}, the internal startup circuit is disabled, blocking IHV from flowing into the HV pin. Once the IC turns on, C_{VDD} is the only energy source to supply the IC consumption current before the PWM starts to switch. Thus, CVDD must be large enough to prevent V_{DD} from dropping to V_{DD-OFF} before the power can be delivered from the auxiliary winding. The V_{DD} capacitance tolerance is an important factor to consider for C_{DD} selection. Connecting a 22 μF capacitor between the V_{DD} and GND pins is recommended to ensure the system stability across a wide operating temperature range.

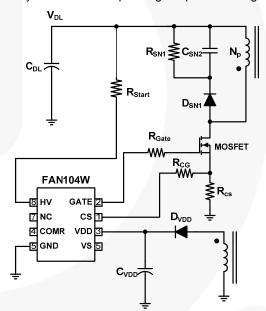


Figure 30. HV Startup Circuit

Protections

The FAN104W self-protection functions include V_{DD} Over-Voltage-Protection (V_{DD} OVP), Over-Temperature-Protection (OTP), VS Over-Voltage Protection (VSOVP), CS pin short-circuit protection, brownout protection, and VS pin low-side resistor open/short protection, and high-side resistor-open protection. The V_{DD} OVP, brownout protection, VS pin low-side resistor short protection, VS pin high-side open protection, and CS pin short-circuit protection are implemented as Auto-Restart Mode. The VSOVP, VS pin low-side resistor open protection and internal OTP are implemented as Latch Mode.

When an Auto-Restart Mode protection is triggered, switching is terminated and the MOSFET remains off, causing V_{DD} to drop. When V_{DD} reaches the V_{DD} turn-off voltage of 5 V; the protection is reset, the internal startup circuit is enabled, and the supply current drawn from the HV pin charges the hold-up capacitor. When V_{DD} reaches the turn-on voltage of 16 V, normal operation resumes. In this manner, Auto-Restart alternately enables and disables the switching of the MOSFET until the abnormal condition is eliminated, as shown in Figure 31.

When a Latch Mode protection is triggered, PWM switching is terminated and the MOSFET remains off, causing V_{DD} to drop. When V_{DD} drops to the V_{DD} turn-off voltage of 5 V, the internal startup circuit is enabled without resetting the protection and the supply current drawn from HV pin charges the hold-up capacitor. Since the protection is not reset, the IC does not resume PWM switching even when V_{DD} reaches the turn-on voltage of 16 V, disabling HV startup circuit. Then, V_{DD} drops again down to 5 V. In this manner, a Latch Mode protection alternately charges and discharges V_{DD} until there is no more energy in DC link capacitor. The protection is reset when V_{DD} drops to 2.5 V, which is allowed only after power supply is unplugged from the AC line, as shown in Figure 32.

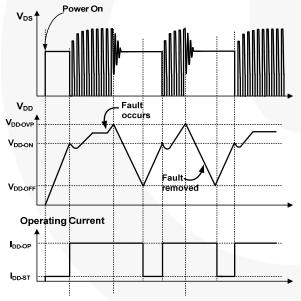


Figure 31. Auto-Restart Mode Operation

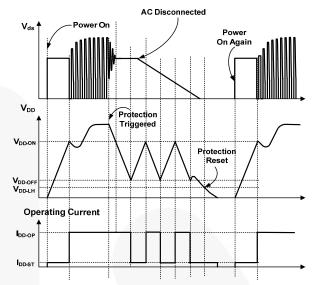


Figure 32. Latch-Mode Operation

Leading-Edge Blanking (LEB)

Each time the power MOSFET is switched on, a turn-on spike occurs at the sense resistor. To avoid premature termination of the switching pulse, a 150 ns leading-edge blanking time is built in. Conventional RC filtering can therefore be omitted. During this blanking period, the current-limit comparator is disabled and it cannot switch off the gate driver.

Noise Immunity

Noise from the current sense or the control signal can cause significant pulse width jitter, particularly in Continuous-Conduction Mode. While slope compensation helps alleviate these problems, further precautions should still be taken. Good placement and layout practices should be followed. Avoiding long PCB traces and component leads, locating compensation and filter components near the FAN104W, and increasing the power MOS gate resistance is advised.

Physical Dimensions

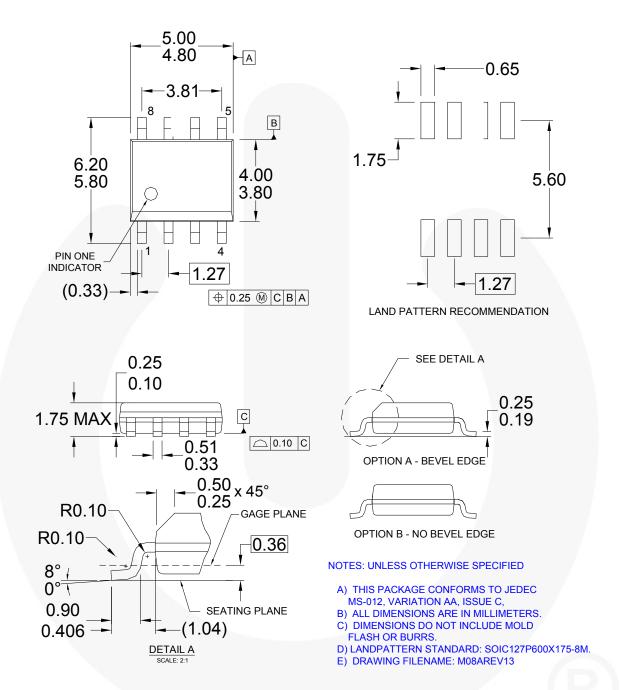


Figure 33. 8-Lead, SOIC, JEDEC MS-012, .150" Narrow Body

Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings: http://www.fairchildsemi.com/packaging/.





TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

2Cool™ F-PEST FRFET® AccuPower™ Global Power Resource AX-CAP™* BitSiC™ GreenBridge™ Green FPS™ Build it Now™ Green FPS™ e-Series™ CorePLUS™ CorePOWER™ Gmax™ GTO™ CROSSVOLT"

IntelliMAX™ CTL TM ISOPLANARTI Current Transfer Logic™ Making Small Speakers Sound Louder DEUXPEED®

and Better Dual Cool™ EcoSPARK[®] MegaBuck™ MICROCOUPLER™ EfficientMax™

ESBC™ •® MicroPak™ MicroPak2™ Fairchild® MillerDrive™ Fairchild Semiconductor® MotionMax™ FACT Quiet Series mWSaver™ FACT® OptoHiT^{TI}

MicroFET[®] **OPTOLOGIC®** FastvCore™ **OPTOPLANAR®** FETBench™

PowerTrench® PowerXSTM

Programmable Active Droop™

OFET OST Quiet Series™ RapidConfigure™

Saving our world, 1mW/W/kW at a time™

SignalWise^{TI} SmartMax™ SMART START™

Solutions for Your Success™

SPM[®] STEALTH™ SuperFET[®] SuperSOT™-3 SuperSOT™-6 SuperSOT™-8 SupreMOS® SyncFET* Sync-Lock™ SYSTEM SERVERALS

wer franchise TinyBoost^T TinyBuck™ TinyCalc™ TinyLogic TINYOPTO™ TinyPower™ TinyPWM™ TinyWire™ TranSiC™ TriFault Detect™ TRUECURRENT®* μSerDes™

The Power Franchise®

 μ_{sa} UHC Ultra FRFET™ UniFET VCXTM VisualMax™ VoltagePlus™ XSTM

* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

FPS™

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- 2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com,

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms				
Datasheet Identification		Definition		
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.		
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.		
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.		
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.		

Rev. 163

ON Semiconductor and in are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdt/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and exp

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com N. American Technical Support: 800-282-9855 Toll Free USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative